

Figure 2. Block Diagram

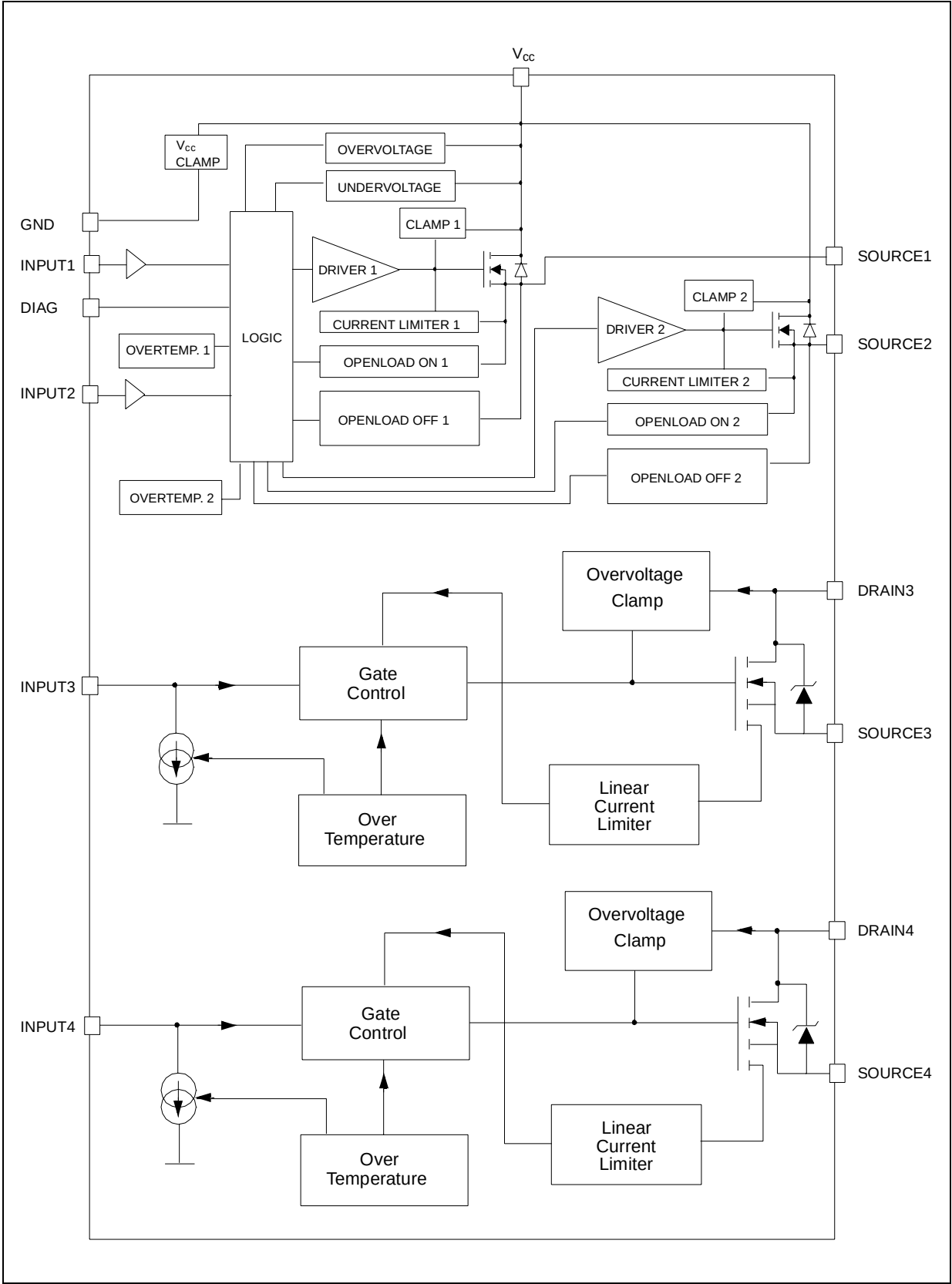
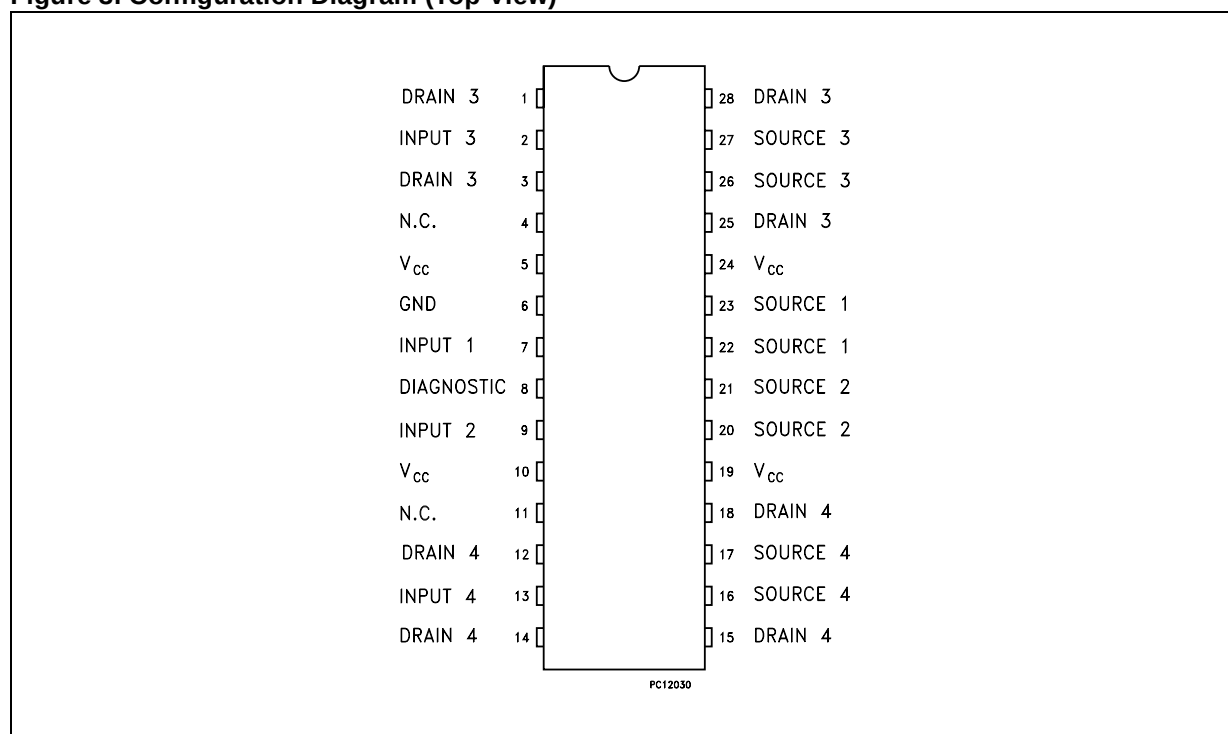


Table 3. Pin Function

No	NAME	FUNCTION
1, 3, 25, 28	DRAIN 3	Drain of Switch 3 (low-side switch)
2	INPUT 3	Input of Switch 3 (low-side switch)
4, 11	N.C.	Not Connected
5, 10, 19, 24	V _{CC}	Drain of Switches 1 and 2 (high-side switches) and Power Supply Voltage
6	GND	Ground of Switches 1 and 2 (high-side switches)
7	INPUT 1	Input of Switch 1 (high-side switches)
8	DIAGNOSTIC	Diagnostic of Switches 1 and 2 (high-side switches)
9	INPUT 2	Input of Switch 2 (high-side switch)
12, 14, 15, 18	DRAIN 4	Drain of switch 4 (low-side switch)
13	INPUT 4	Input of Switch 4 (low-side switch)
16, 17	SOURCE 4	Source of Switch 4 (low-side switch)
20, 21	SOURCE 2	Source of Switch 2 (high-side switch)
22, 23	SOURCE 1	Source of Switch 1 (high-side switch)
26, 27	SOURCE 3	Source of Switch 3 (low-side switch)

Figure 3. Configuration Diagram (Top View)**Table 4. Thermal Data**

Symbol	Parameter	Value	Unit
R _{thj-case}	Thermal Resistance Junction-case (High-side switch) MAX	20	°C/W
R _{thj-case}	Thermal Resistance Junction-case (Low-side switch) MAX	20	°C/W
R _{thj-amb}	Thermal Resistance Junction-ambient MAX	60	°C/W

ABSOLUTE MAXIMUM RATINGS

Table 5. Dual High Side Switch

Symbol	Parameter	Value	Unit
V_{CC}	DC Supply Voltage	41	V
$-V_{CC}$	Reverse DC Supply Voltage	- 0.3	V
$-I_{GND}$	DC Reverse Ground Pin Current	- 200	mA
I_{OUT}	DC Output Current	Internally Limited	A
$-I_{OUT}$	Reverse DC Output Current	- 6	A
I_{IN}	DC Input Current	+/- 10	mA
I_{STAT}	DC Status Current	+/- 10	mA
V_{ESD}	Electrostatic Discharge (Human Body Model: $R=1.5K\Omega$; $C=100pF$)		
	- INPUT	4000	V
	- STATUS	4000	V
	- OUTPUT	5000	V
	- V_{CC}	5000	V
P_{tot}	Power Dissipation $T_C=25^\circ C$	6	W
T_j	Junction Operating Temperature	Internally Limited	$^\circ C$
T_C	Case Operating Temperature	- 40 to 150	$^\circ C$
T_{stg}	Storage Temperature	- 55 to 150	$^\circ C$

Table 6. Low Side Switch

Symbol	Parameter	Value	Unit
V_{DS}	Drain-source Voltage ($V_{IN}=0V$)	Internally Clamped	V
V_{IN}	Input Voltage	Internally Clamped	V
I_{IN}	Input Current	+/-20	mA
$R_{IN\ MIN}$	Minimum Input Series Impedance	150	Ω
I_D	Drain Current	Internally Limited	A
I_R	Reverse DC Output Current	-10.5	A
V_{ESD1}	Electrostatic Discharge ($R=1.5K\Omega$, $C=100pF$)	4000	V
V_{ESD2}	Electrostatic Discharge on output pin only ($R=330\Omega$, $C=150pF$)	16500	V
P_{tot}	Power Dissipation ($T_C=25^\circ C$)	6	W
T_j	Operating Junction Temperature	Internally limited	$^\circ C$

ELECTRICAL CHARACTERISTICS FOR DUAL HIGH SIDE SWITCH(8V<V_{CC}<36V; -40°C<T_j<150°C, unless otherwise specified) (Per each channel)**Table 7. Power Outputs**

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
V _{CC} ⁽¹⁾	Operating Supply Voltage		5.5	13	36	V
V _{USD} ⁽¹⁾	Undervoltage Shut-down		3	4	5.5	V
V _{Ov} ⁽¹⁾	Overvoltage Shut-down		36			V
R _{DS(on)}	On State Resistance	I _{OUT} =2A; T _j =25°C			60	mΩ
		I _{OUT} =2A; V _{CC} >8V			120	mΩ
I _S ⁽¹⁾	Supply Current	Off State; V _{CC} =13V; V _{IN} =V _{OUT} =0V		12	40	μA
		Off State; V _{CC} =13V; T _j =25°C; V _{IN} =V _{OUT} =0V		12	25	μA
		On State; V _{CC} =13V		5	7	mA
I _{L(off1)}	Off State Output Current	V _{IN} =V _{OUT} =0V; V _{CC} =36V; T _j =125°C	0		50	μA
I _{L(off2)}	Off State Output Current	V _{IN} =0V; V _{OUT} =3.5V	-75		0	μA
I _{L(off3)}	Off State Output Current	V _{IN} =V _{OUT} =0V; V _{CC} =13V; T _j =125°C			5	μA
I _{L(off4)}	Off State Output Current	V _{IN} =V _{OUT} =0V; V _{CC} =13V; T _j =25°C			3	μA

Note: ⁽¹⁾ Per device.**Table 8. Switching (V_{CC}=13V)**

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
t _{d(on)}	Turn-on Delay Time	R _L =6.5Ω from V _{IN} rising edge to V _{OUT} =1.3V		30		μs
t _{d(off)}	Turn-off Delay Time	R _L =6.5Ω from V _{IN} falling edge to V _{OUT} =11.7V		30		μs
dV _{OUT} /dt _(on)	Turn-on Voltage Slope	R _L =6.5Ω from V _{OUT} =1.3V to V _{OUT} =10.4V		See relative diagram		V/μs
dV _{OUT} /dt _(off)	Turn-off Voltage Slope	R _L =6.5Ω from V _{OUT} =11.7V to V _{OUT} =1.3V		See relative diagram		V/μs

Table 9. Logic Input

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
V _{IL}	Input Low Level				1.25	V
I _{IL}	Low Level Input Current	V _{IN} = 1.25V	1			μA
V _{IH}	Input High Level		3.25			V
I _{IH}	High Level Input Current	V _{IN} = 3.25V			10	μA
V _{I(hyst)}	Input Hysteresis Voltage		0.5			V
V _{ICL}	Input Clamp Voltage	I _{IN} = 1mA I _{IN} = -1mA	6	6.8 -0.7	8	V V

Table 10. Status Pin

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
V _{STAT}	Status Low Output Voltage	I _{STAT} = 1.6 mA			0.5	V
I _{LSTAT}	Status Leakage Current	Normal Operation; V _{STAT} = 5V			10	μA
C _{STAT}	Status Pin Input Capacitance	Normal Operation; V _{STAT} = 5V			100	pF
V _{SCL}	Status Clamp Voltage	I _{STAT} = 1mA I _{STAT} = - 1mA	6	6.8 -0.7	8	V V

ELECTRICAL CHARACTERISTICS FOR DUAL HIGH SIDE SWITCH (continued)

Table 11. Protections

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
T_{TSD}	Shut-down Temperature		150	175	200	°C
T_R	Reset Temperature		135			°C
T_{hyst}	Thermal Hysteresis		7	15		°C
t_{SDL}	Status Delay in Overload Conditions	$T_j > T_{TSD}$			20	μs
I_{lim}	Current limitation	$T_j = 125^\circ\text{C}$ $5.5\text{V} < V_{CC} < 36\text{V}$	6 8.5	9	15 15 15	A A A
V_{demag}	Turn-off Output Clamp Voltage	$I_{OUT} = 2\text{A}$; $L = 6\text{mH}$	$V_{CC} - 41$	$V_{CC} - 48$	$V_{CC} - 55$	V

Table 12. Openload Detection

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
I_{OL}	Openload ON State Detection Threshold	$V_{IN} = 5\text{V}$	50	100	200	mA
$t_{DOL(on)}$	Openload ON State Detection Delay	$I_{OUT} = 0\text{A}$			200	μs
V_{OL}	Openload OFF State Voltage Detection Threshold	$V_{IN} = 0\text{V}$	1.5	2.5	3.5	V
$T_{DOL(off)}$	Openload Detection Delay at Turn Off				1000	μs

ELECTRICAL CHARACTERISTICS FOR LOW SIDE SWITCHES

(-40°C < T_j < 150°C, unless otherwise specified)

Table 13. Off

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
V_{CLAMP}	Drain-source Clamp Voltage	$V_{IN} = 0\text{V}$; $I_D = 3.5\text{A}$	40	45	55	V
V_{CLTH}	Drain-source Clamp Threshold Voltage	$V_{IN} = 0\text{V}$; $I_D = 2\text{mA}$	36			V
V_{INTH}	Input Threshold Voltage	$V_{DS} = V_{IN}$; $I_D = 1\text{mA}$	0.5		2.5	V
I_{ISS}	Supply Current from Input Pin	$V_{DS} = 0\text{V}$; $V_{IN} = 5\text{V}$		100	150	μA
V_{INCL}	Input-Source Clamp Voltage	$I_{IN} = 1\text{mA}$ $I_{IN} = -1\text{mA}$	6 -1.0	6.8	8 -0.3	V
I_{DSS}	Zero Input Voltage Drain Current ($V_{IN} = 0\text{V}$)	$V_{DS} = 13\text{V}$; $V_{IN} = 0\text{V}$; $T_j = 25^\circ\text{C}$ $V_{DS} = 25\text{V}$; $V_{IN} = 0\text{V}$			30 75	μA

Table 14. On

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
$R_{DS(on)}$	Static Drain-source On Resistance	$V_{IN} = 5\text{V}$; $I_D = 3.5\text{A}$; $T_j = 25^\circ\text{C}$ $V_{IN} = 5\text{V}$; $I_D = 3.5\text{A}$			60 120	mΩ

ELECTRICAL CHARACTERISTICS FOR LOW SIDE SWITCHES (continued)(T_j=25°C, unless otherwise specified)**Table 15. Dynamic**

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
g _{fs} (*)	Forward Transconductance	V _{DD} =13V; I _D =3.5A		9		S
C _{oss}	Output Capacitance	V _{DS} =13V; f=1MHz; V _{IN} =0V		220		pF

Table 16. Switching

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
t _{d(on)}	Turn-on Delay Time	V _{DD} =15V; I _D =3.5A V _{gen} =5V; R _{gen} =R _{IN MIN} =150Ω		100	300	ns
t _r	Rise Time			470	1500	ns
t _{d(off)}	Turn-off Delay Time			500	1500	ns
t _f	Fall Time			350	1000	ns
t _{d(on)}	Turn-on Delay Time	V _{DD} =15V; I _D =3.5A V _{gen} =5V; R _{gen} =2.2KΩ		0.75	2.3	μs
t _r	Rise Time			4.6	14.0	μs
t _{d(off)}	Turn-off Delay Time			5.4	16.0	μs
t _f	Fall Time			3.6	11.0	μs
(di/dt) _{on}	Turn-on Current Slope	V _{DD} =15V; I _D =3.5A V _{gen} =5V; R _{gen} =R _{IN MIN} =150Ω		6.5		A/μs
Q _i	Total Input Charge	V _{DD} =12V; I _D =3.5A; V _{IN} =5V I _{gen} =2.13mA		18		nC

Table 17. Source Drain Diode

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
V _{SD} (*)	Forward On Voltage	I _{SD} =3.5A; V _{IN} =0V		0.8		V
t _{rr}	Reverse Recovery Time	I _{SD} =3.5A; di/dt=20A/μs V _{DD} =30V; L=200μH		220		ns
Q _{rr}	Reverse Recovery Charge			0.28		μC
I _{RRM}	Reverse Recovery Current			2.5		A

Note: (*) Pulsed: Pulse duration = 300μs, duty cycle 1.5%

Table 18. Protections (-40°C < T_j < 150°C, unless otherwise specified)

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
I _{lim}	Drain Current Limit	V _{IN} =5V; V _{DS} =13V	6	9	12	A
		V _{IN} =5V; V _{DS} =13V; T _j =125°C	6.5		12	A
t _{dlim}	Step Response Current Limit	V _{IN} =5V; V _{DS} =13V		4.0		μs
T _{jsh}	Overtemperature Shutdown		150	175		°C
T _{jrs}	Overtemperature Reset		135			°C
I _{gf}	Fault Sink Current	V _{IN} = 5V; V _{DS} =13V; T _j =T _{jsh}		15		mA
E _{as}	Single Pulse Avalanche Energy	starting T _j =25°C; V _{DD} =24V V _{IN} =5V; R _{gen} =R _{IN MIN} =150Ω; L=24mH	200			mJ

DUAL HIGH-SIDE SWITCH

Figure 4. Switching Time Waveforms

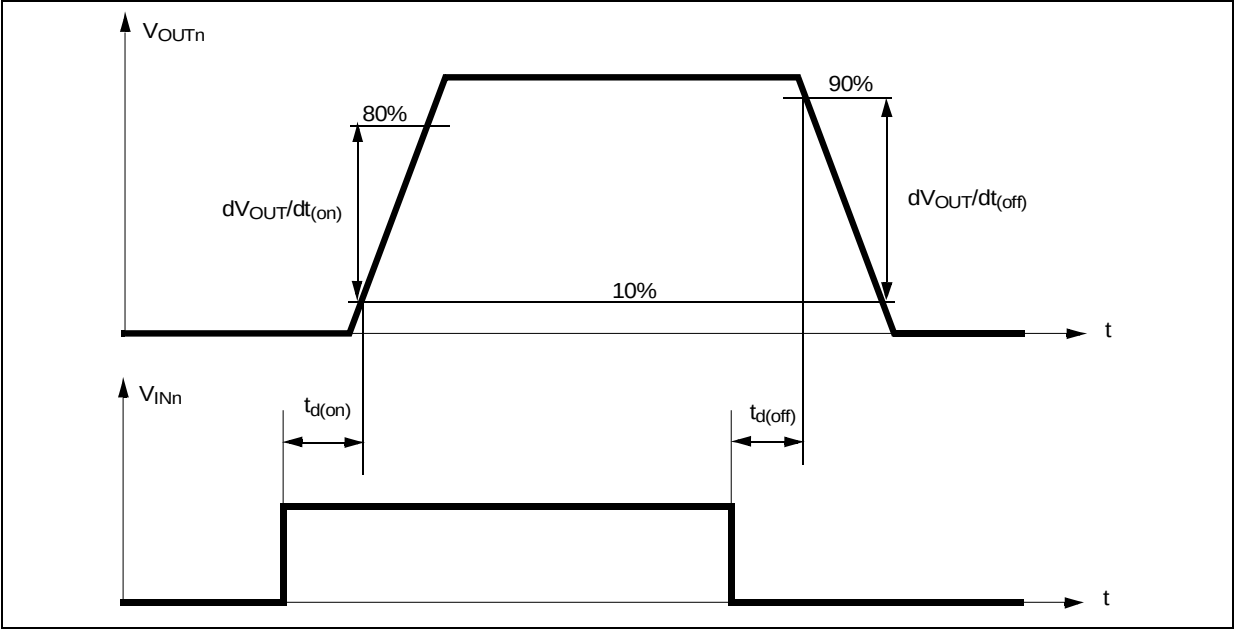


Table 19. Truth Table

CONDITIONS	INPUT	OUTPUT	STATUS
Normal Operation	L	L	H
	H	H	H
Current Limitation	L	L	H
	H	X	($T_j < T_{TSD}$) H
	H	X	($T_j > T_{TSD}$) L
Overtemperature	L	L	H
	H	L	L
Undervoltage	L	L	X
	H	L	X
Overvoltage	L	L	H
	H	L	H
Output Voltage > V_{OL}	L	H	L
	H	H	H
Output Current < I_{OL}	L	L	H
	H	H	L

Figure 5.

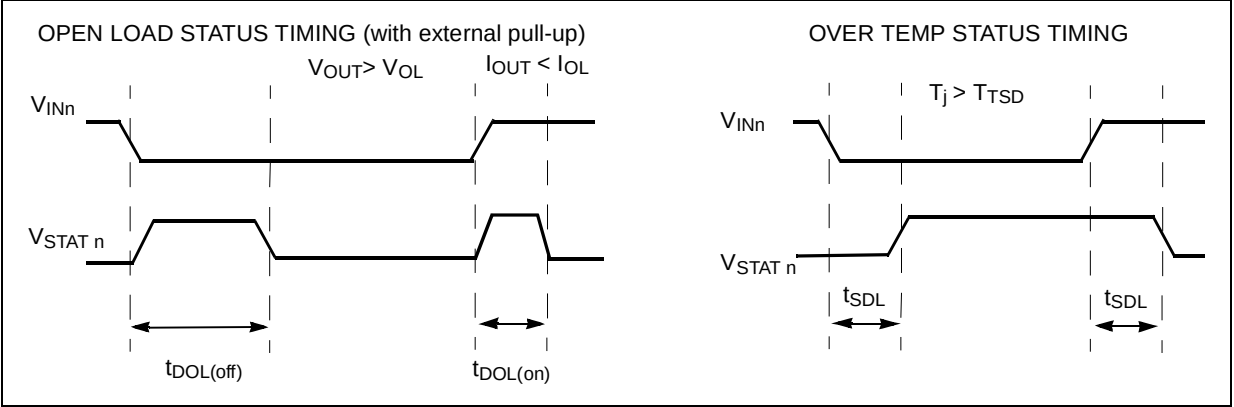


Figure 6. Typical Application Diagram

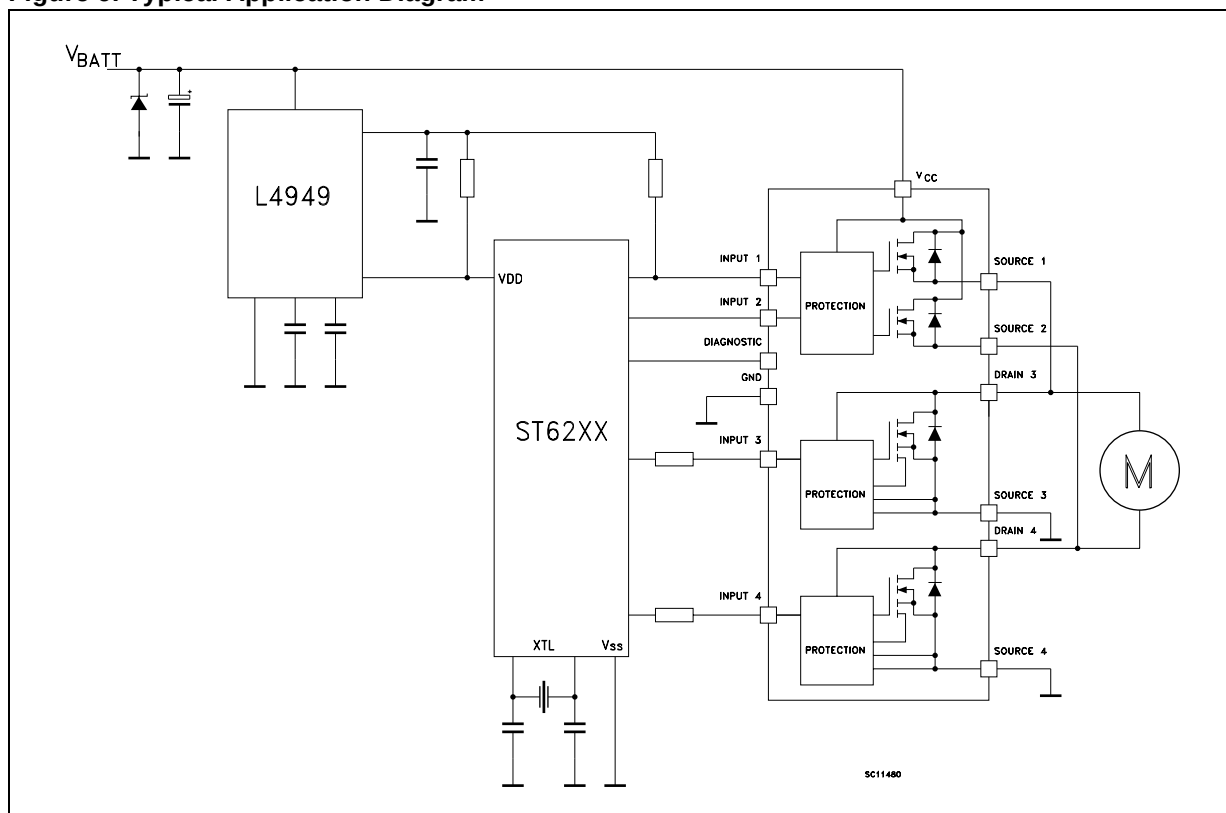
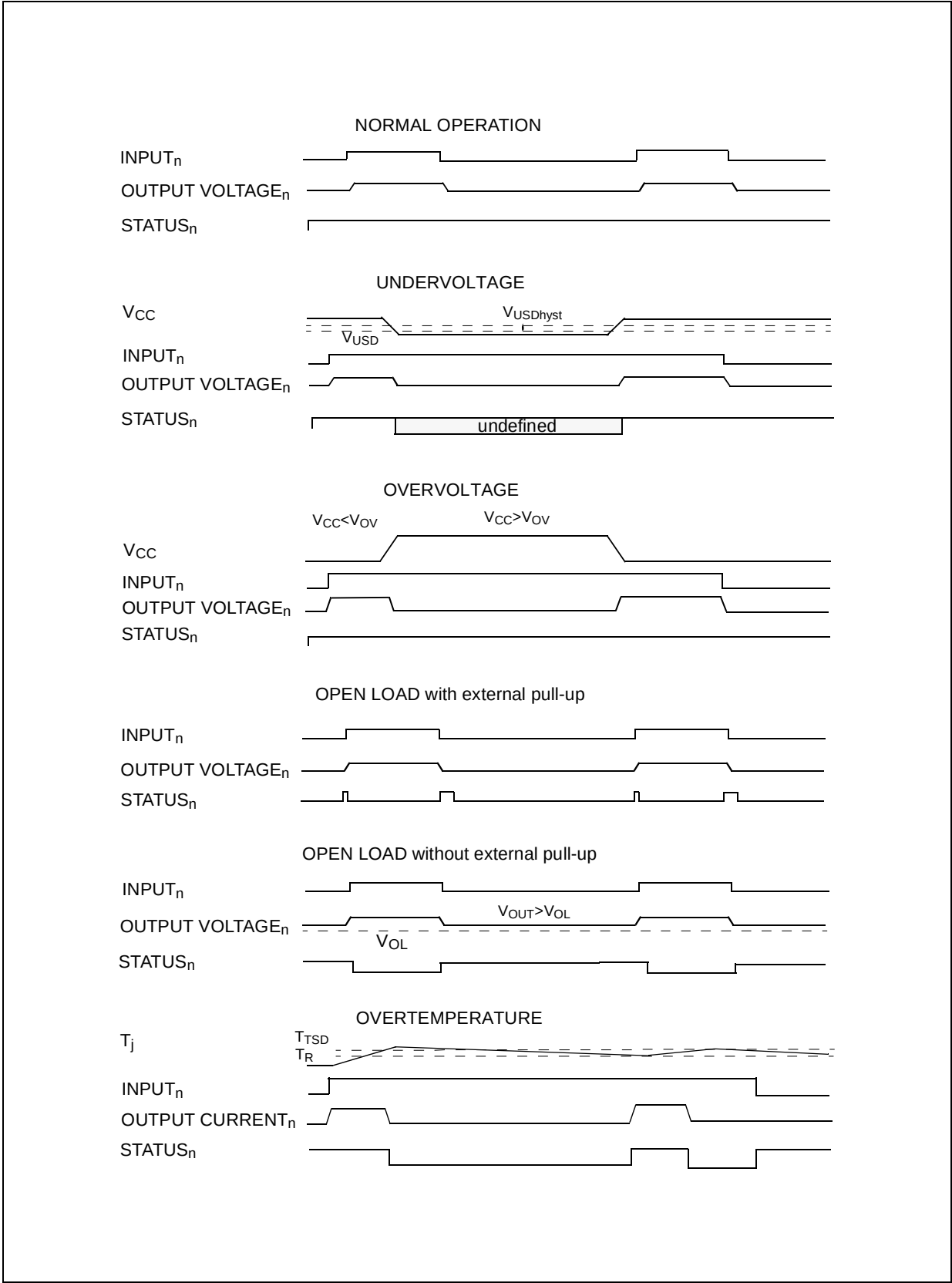


Figure 7. Waveforms



Electrical Characterization For Dual High Side Switch

Figure 8. Off State Output Current

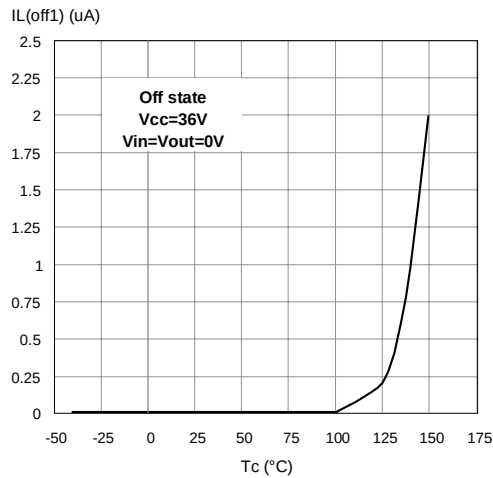


Figure 11. Input Clamp Voltage

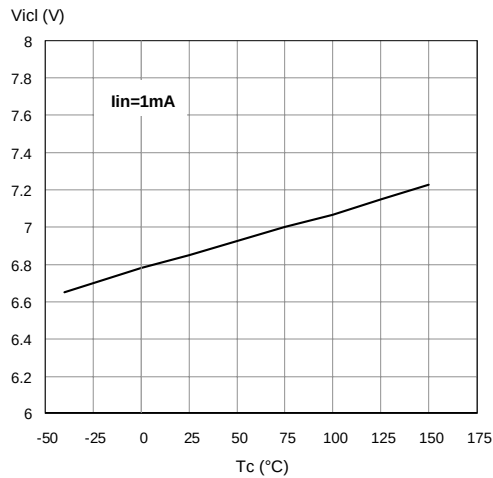


Figure 9. High Level Input Current

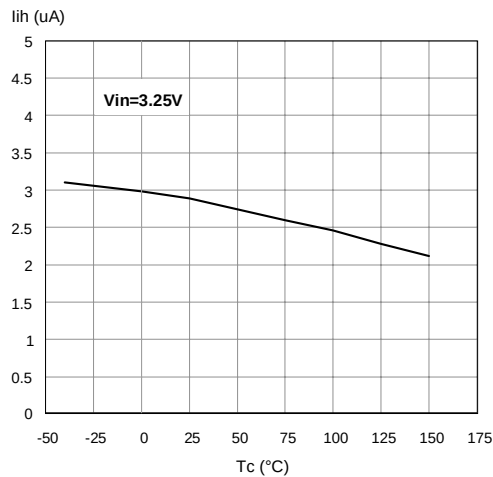


Figure 12. Input High Level

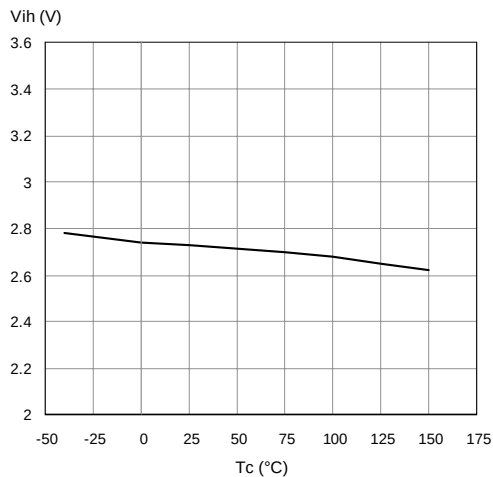


Figure 10. Input Low Level

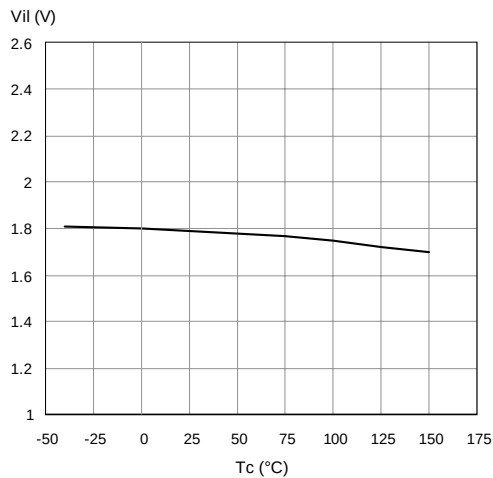
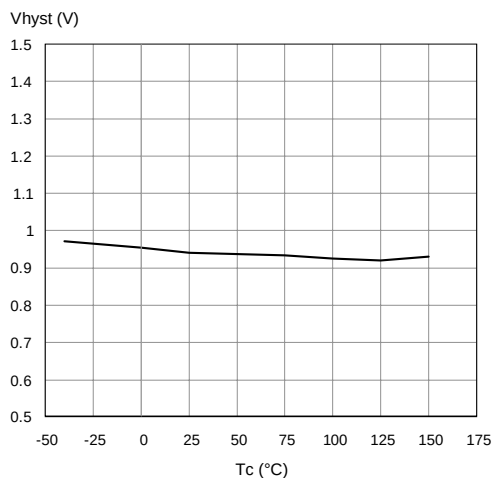


Figure 13. Input Hysteresis Voltage



Electrical Characterization For Dual High Side Switch (continued)

Figure 14. Overvoltage Shutdown

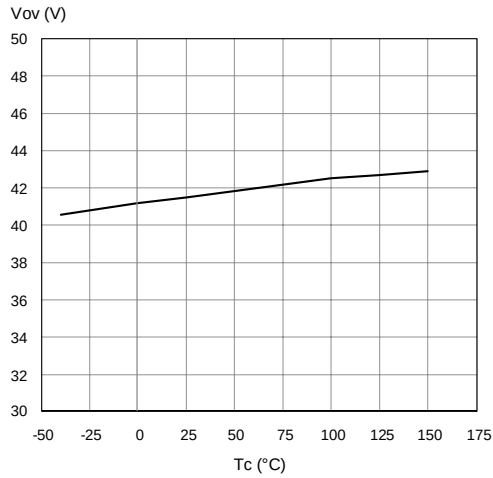


Figure 17. I_{LIM} Vs T_{case}

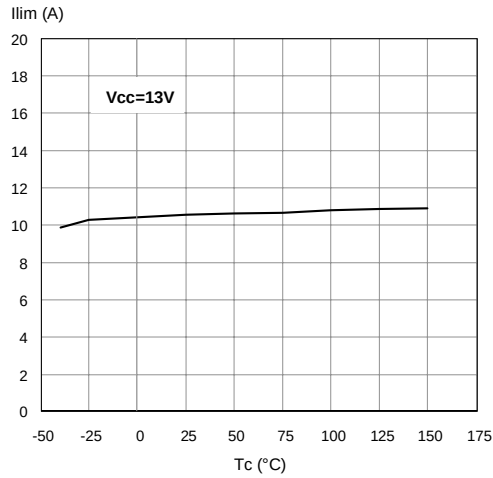


Figure 15. Turn-on Voltage Slope

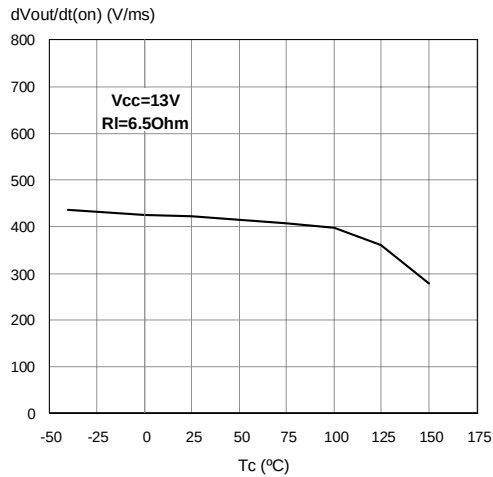


Figure 18. Turn-off Voltage Slope

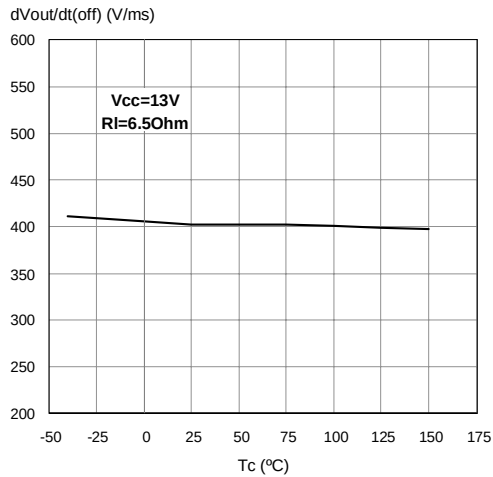


Figure 16. On State Resistance Vs T_{case}

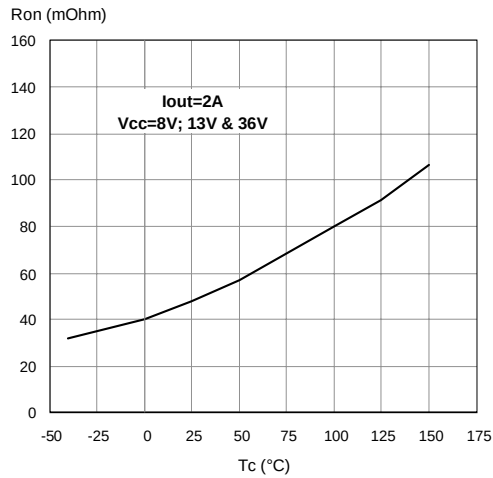
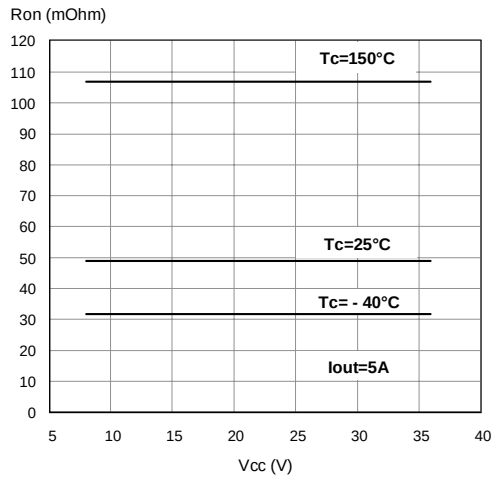


Figure 19. On State Resistance Vs V_{CC}



Electrical Characterization For Dual High Side Switch (continued)

Figure 20. Status Leakage Current

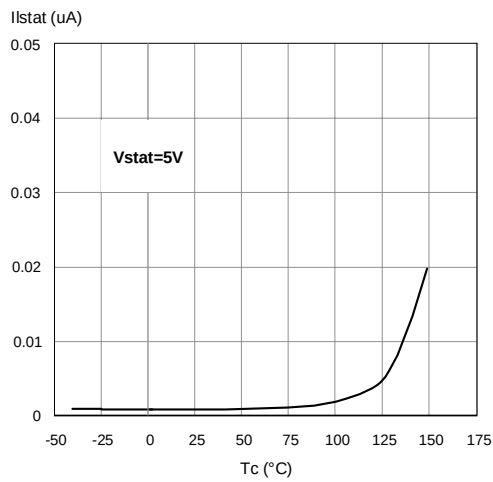


Figure 23. Status Low Output Voltage

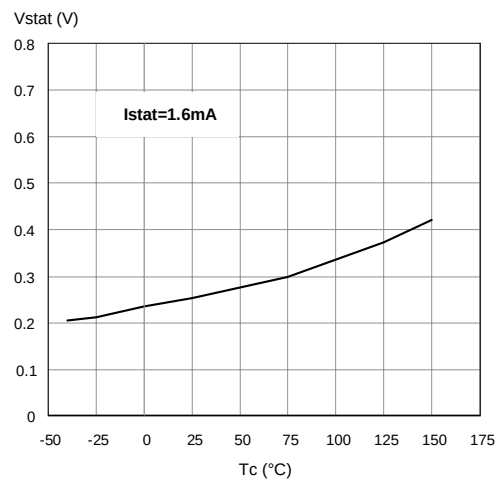


Figure 21. Openload On State Detection Threshold

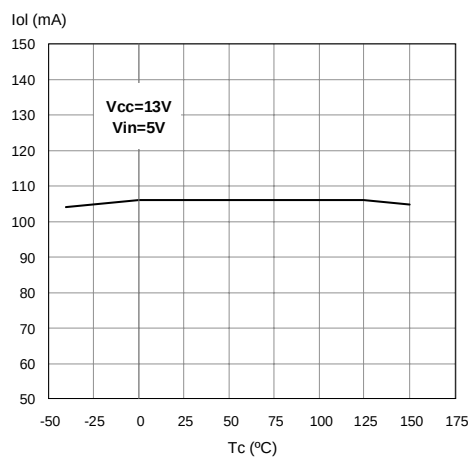


Figure 24. Openload Off State Voltage Detection Threshold

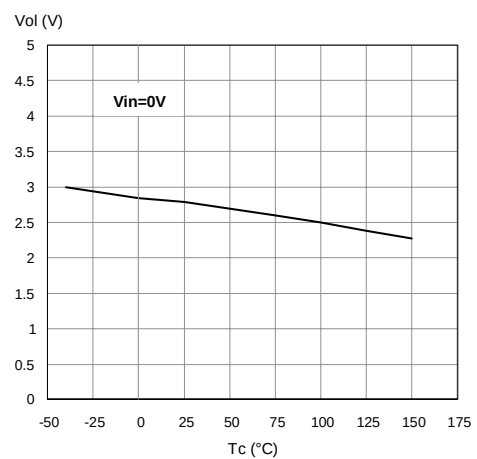
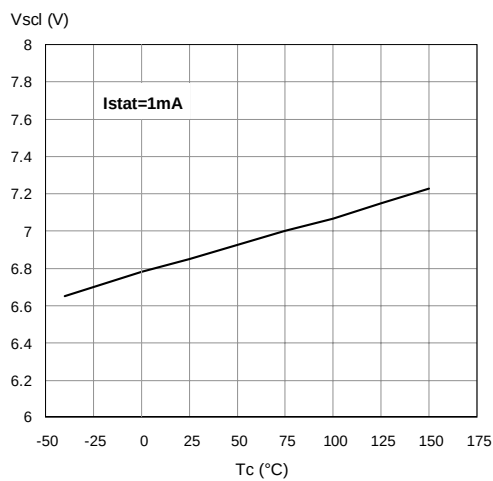


Figure 22. Status Clamp Voltage



Electrical Characterization For Low Side Switches

Figure 25. Static Drain Source On Resistance

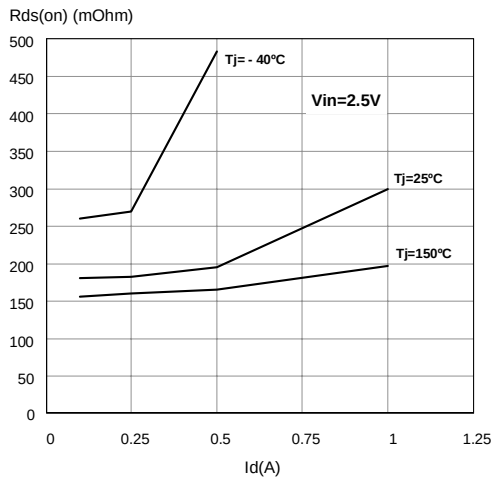


Figure 26. Transconductance

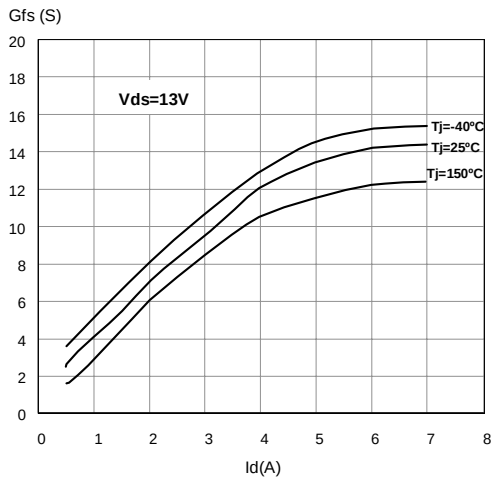


Figure 27. Turn On Current Slope

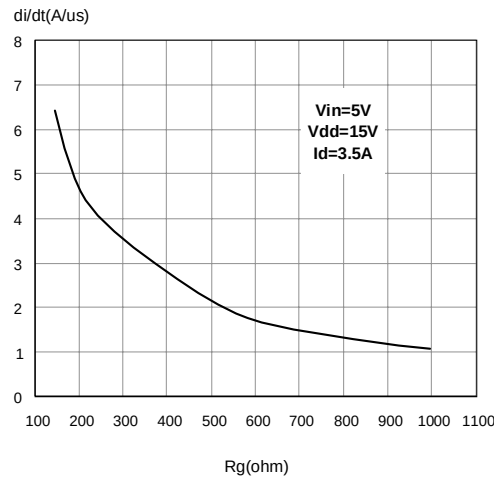


Figure 28. Derating Curve

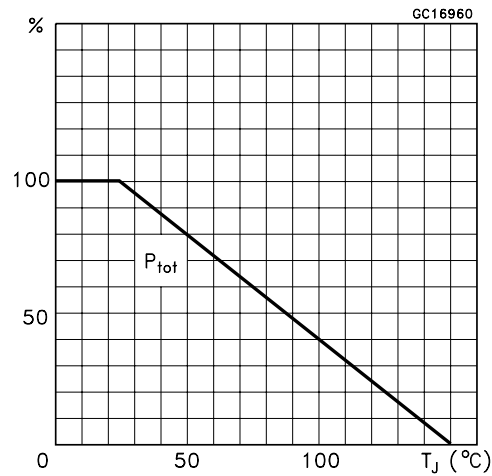


Figure 29. Transfer Characteristics

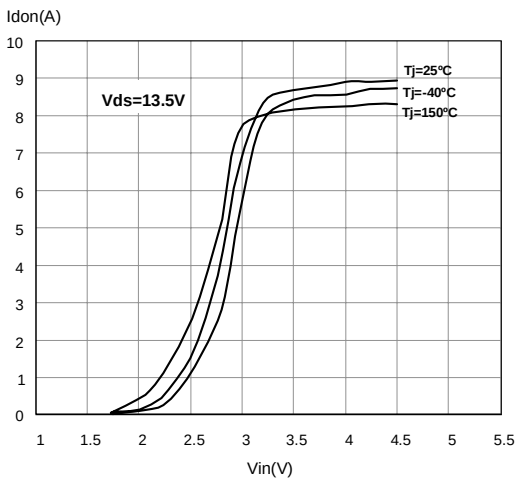
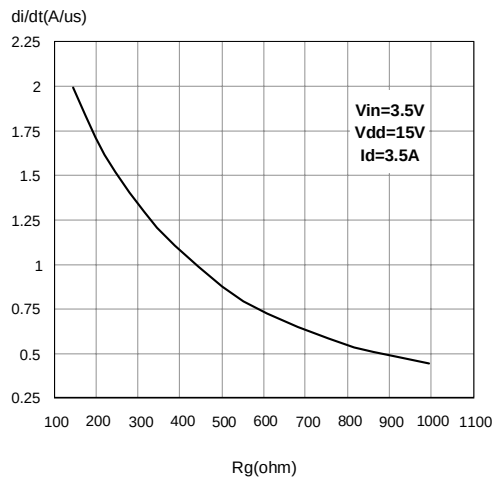


Figure 30. Turn On Current Slope



Electrical Characterization For Low Side Switches (continued)

Figure 31. Input Voltage Vs. Input Charge

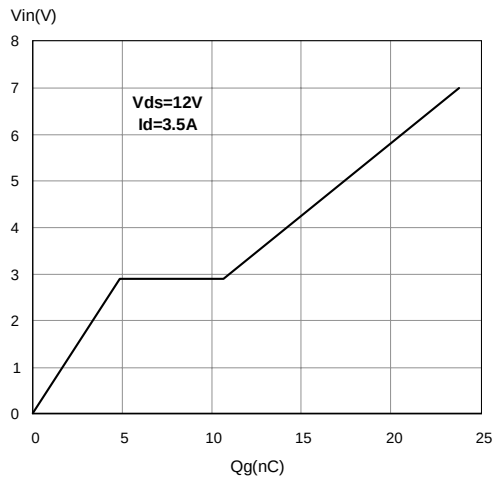


Figure 34. Capacitance Variations

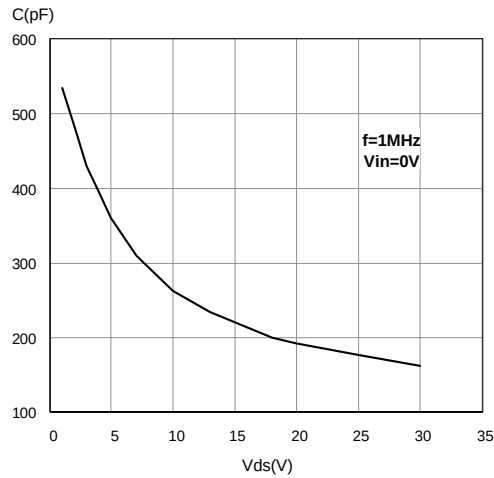


Figure 32. Switching Time Resistive Load

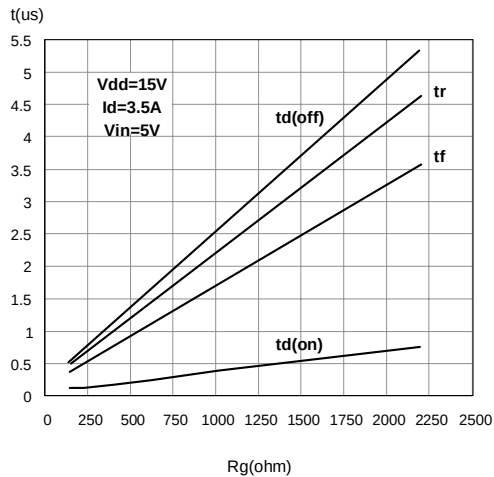


Figure 35. Switching Time Resistive Load

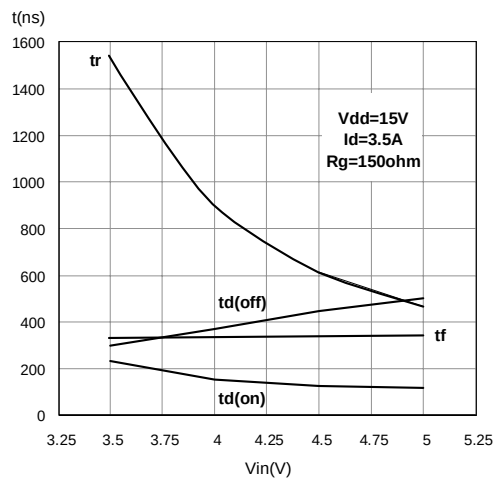


Figure 33. Output Characteristics

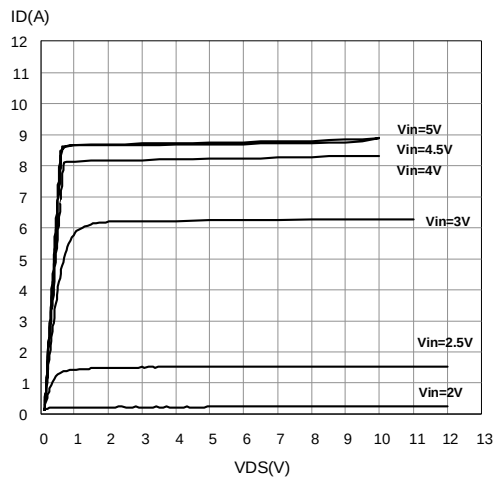
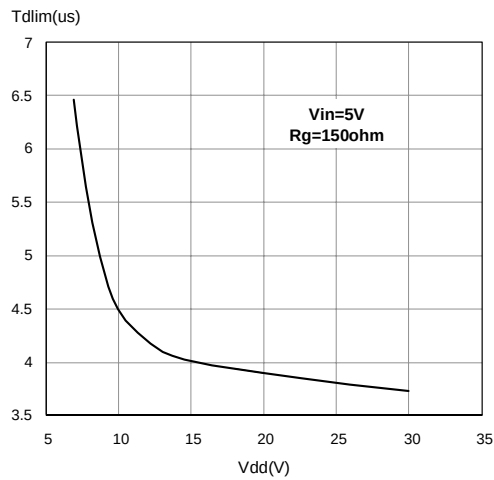


Figure 36. Step Response Current Limit



Electrical Characterization For Low Side Switches (continued)

Figure 37. Source-Drain Diode Forward Characteristics

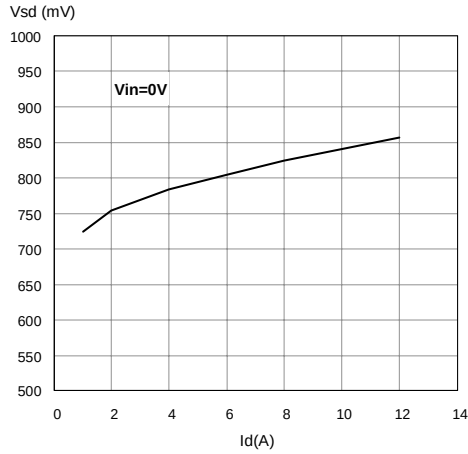


Figure 38. Static Drain-Source On resistance Vs. Input Voltage

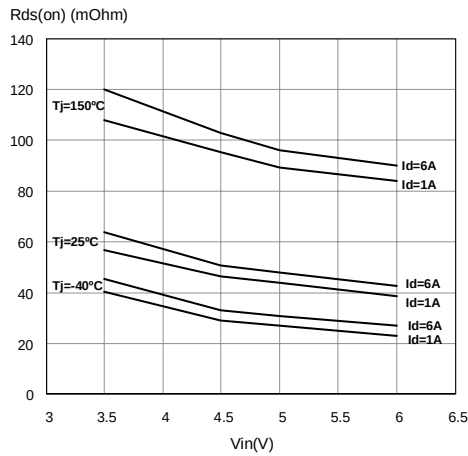


Figure 39. Normalized Input Threshold Voltage Vs. Temperature

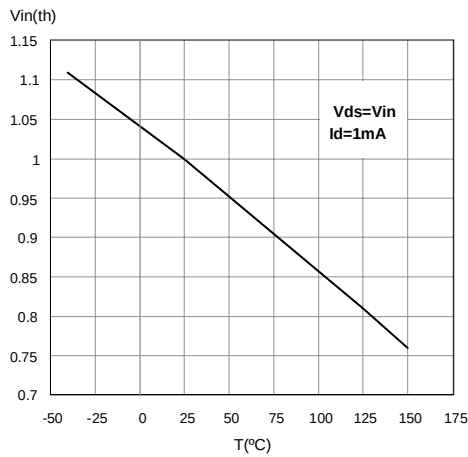


Figure 40. Static Drain-Source On Resistance Vs. Id

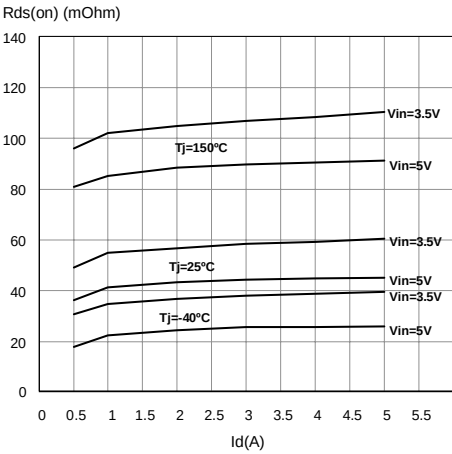


Figure 41. Static Drain-Source On resistance Vs. Input Voltage

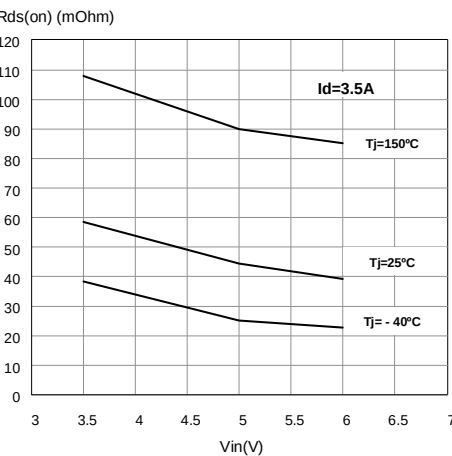
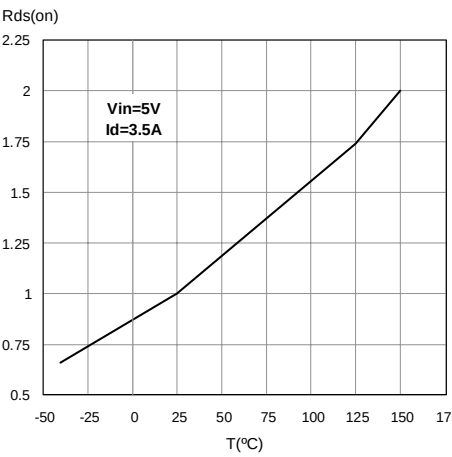


Figure 42. Normalized On Resistance Vs. Temperature



Electrical Characterization For Low Side Switches (continued)

Figure 43. Turn off drain source voltage slope

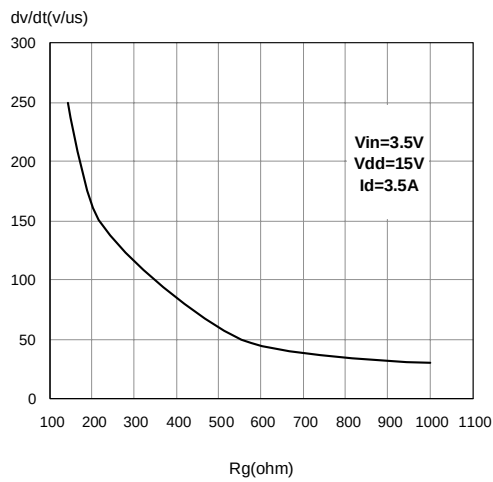


Figure 45. Turn off drain source voltage slope

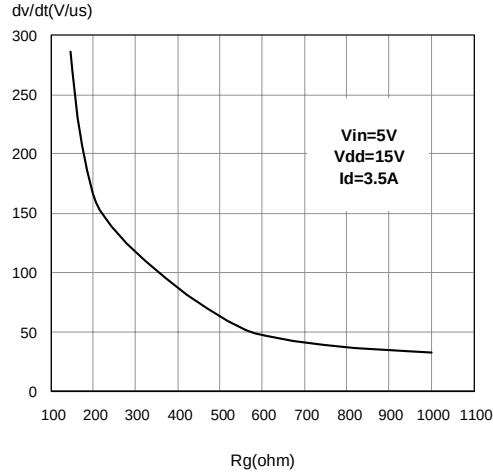


Figure 44. Current Limit Vs. Junction Temperature

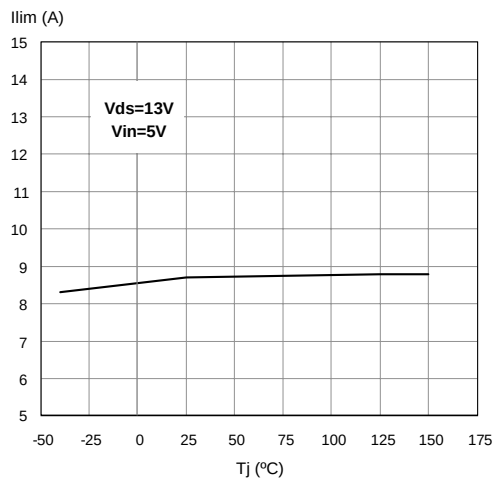


Table 20. SO-28 Mechanical Data

Symbol	millimeters		
	Min	Typ	Max
A			2.65
a1	0.10		0.30
b	0.35		0.49
b1	0.23		0.32
C		0.50	
c1		45° (typ.)	
D	17.7		18.1
E	10.00		10.65
e		1.27	
e3		16.51	
F	7.40		7.60
L	0.40		1.27
S		8° (max.)	

Figure 46. SO-28 Package Dimensions

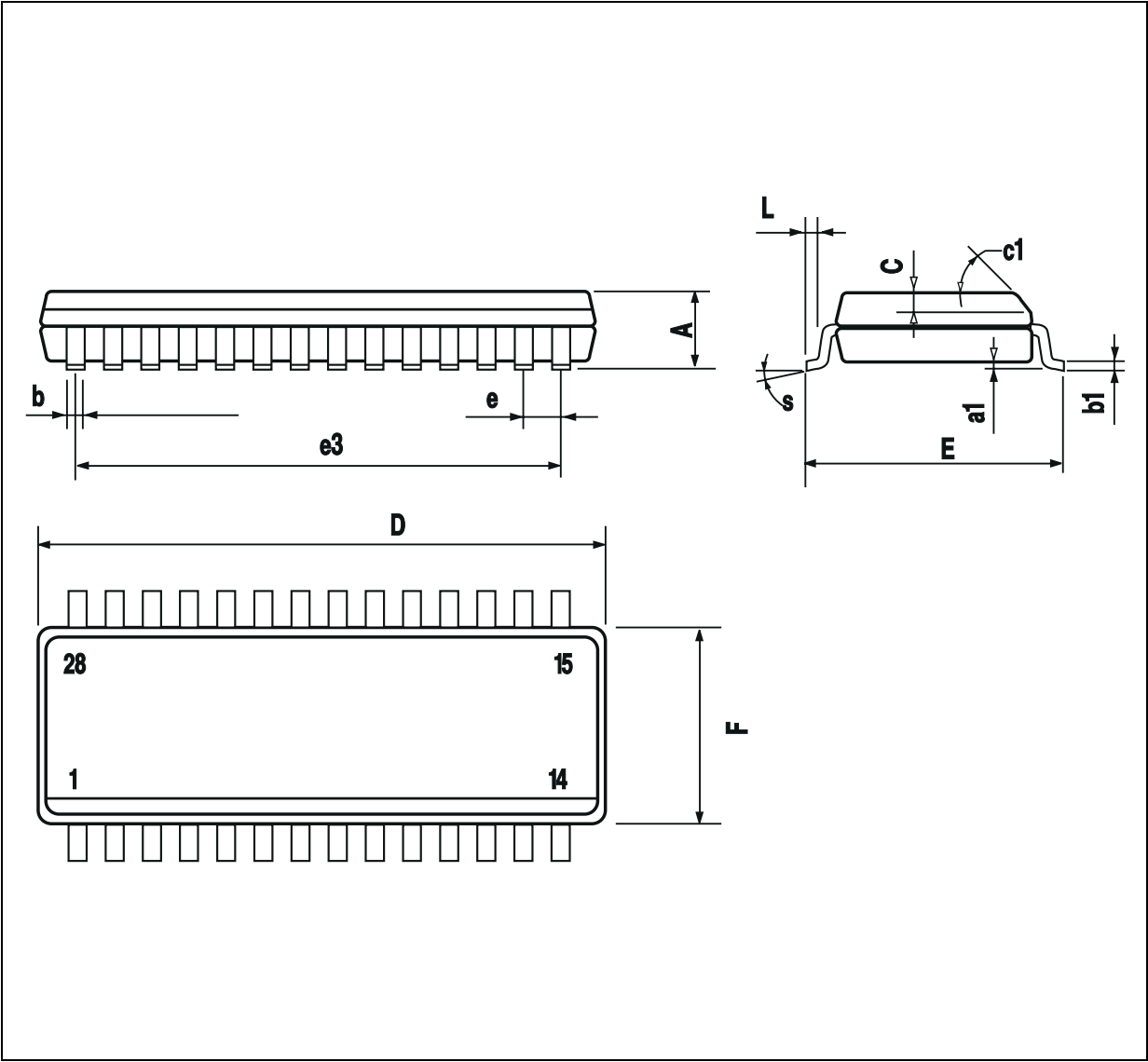


Figure 47. SO-28 Tube Shipment (No Suffix)

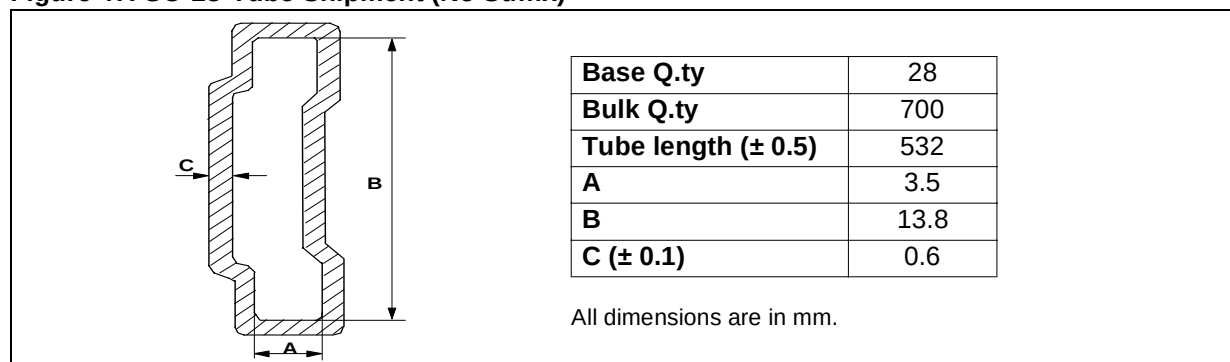
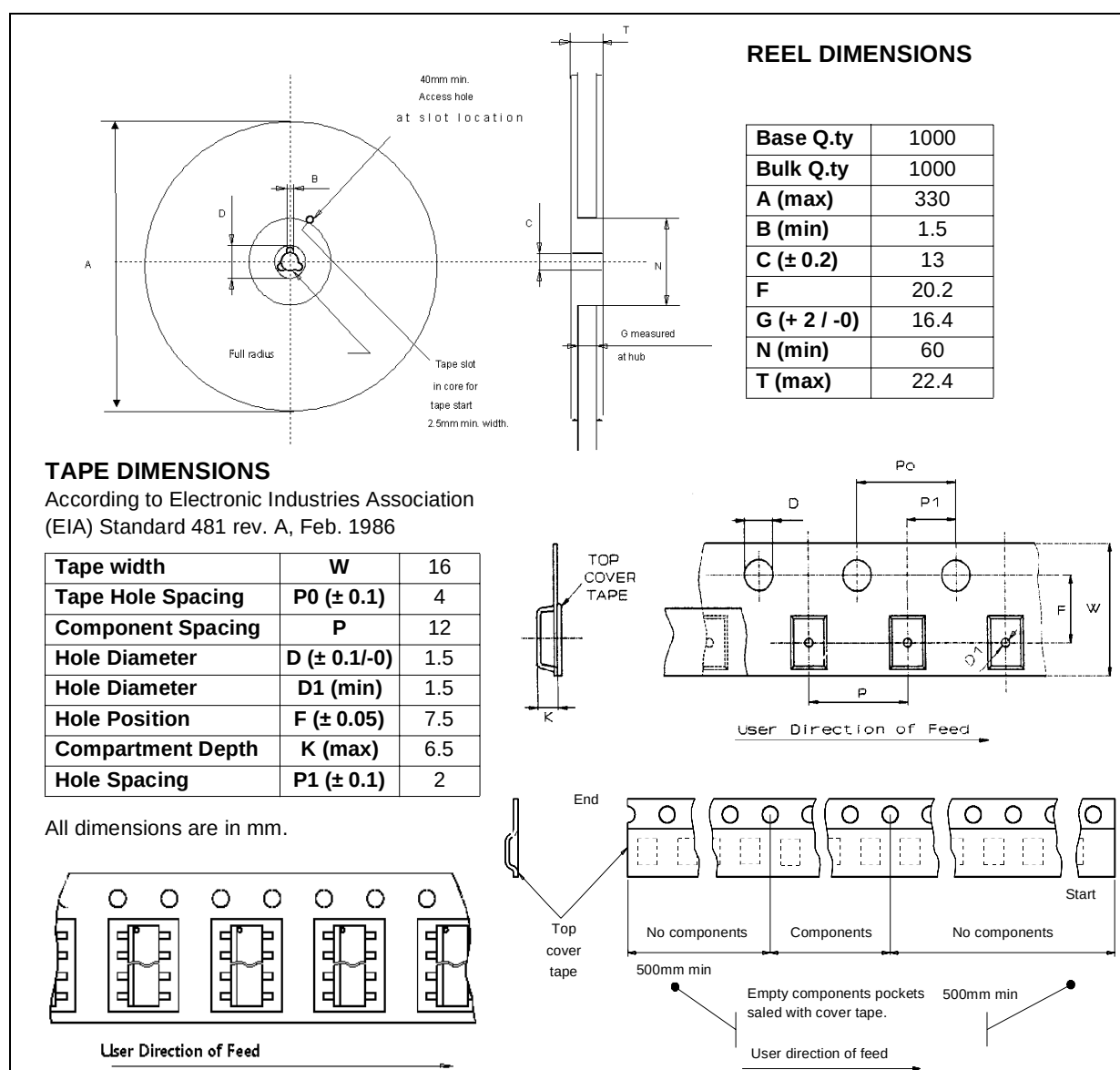


Figure 48. Tape And Reel Shipment (Suffix "TR")



VN772K-E

REVISION HISTORY

Date	Revision	Description of Changes
Sep. 2004	1	- First Issue.

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